## UV/Thermally Induced Isomerization of Spiropyran on MoS<sub>2</sub> Lattice

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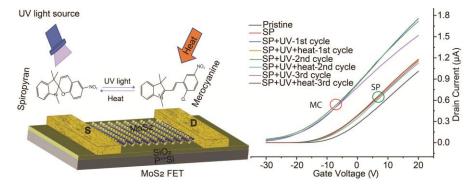
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**Abstract**: Nanotechnology is being considered as a mainstream technology of the 21<sup>st</sup> century due to its aspects of observing and modifying matter at the nano level. Molecules with very specific functional groups can be modulated by outside stimuli are of great interest for sensing and optoelectronics. In this report, we observe the photo/thermal induced structural switching of spiropyran (1',3'-Dihydro-1',3',3'-trimethyl-6-nitrospiro[2H-1-benzopyran-2,2'-(2H)-indole]) molecule through electrical property measurement by MoS<sub>2</sub>-FET (Fig 1a shows the illustration of molecular switching on MoS<sub>2</sub>-FET). Well controlled functionalization of MoS<sub>2</sub> by spiropyran (SP) can be possible by the external photon irradiation. The conformational change of the spiropyran between spiropyran and merocyanine (MC) was monitored, shown I Fig 1b. TOF-SIMS measurement confirms the presence of spiropyran over the MoS<sub>2</sub> after functionalization. Raman spectroscopy confirms the n-doping of both SP and MC.



**Fig. 1** (a) Illustration of SP/MC isomerization on MoS<sub>2</sub>-FET, (b)  $I_d$ - $V_g$  cycles induced by UV/thermal heat.

## References

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